



Manufacturers	Intel Corp
Package/Case	TSOP-56
Product Type	Programmable Logic ICs
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for JS28F128M29EWL or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours. [RFQ](#)

General Description

JS28F128M29EWL is a flash memory device manufactured by Micron Technology. It is a high-performance, low-power, multi-level cell (MLC) NAND flash memory designed for use in a wide range of applications such as automotive, industrial, and networking.

Features

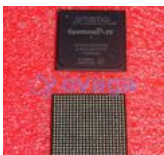
- 128 Mb density
- Multi-level cell (MLC) NAND flash technology
- x8 and x16 memory interfaces
- Operating voltage range of 2.7V to 3.6V
- High performance with a read speed of up to 120MB/s and a write speed of up to 80MB/s
- Low power consumption
- Built-in error correction code (ECC) and wear leveling algorithms

Application

- Automotive: infotainment systems, navigation systems, telematics, and advanced driver assistance systems (ADAS)
- Industrial: embedded systems, robotics, control systems, and instrumentation
- Networking: routers, switches, and other network equipment

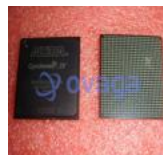


Related Products



[EP4CE15F2317N](#)

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FBGA-484



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Intel Corp
BGA896



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